

# Scalable Metal Mesh Filters for Low Cost THz applications

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Metalmaterial structures are useful for controlling and manipulating THz waves [1]. Among various types of metamaterial-based THz devices, metal mesh bandpass filters have been widely used [2]. In this paper we investigate conventional and trapped mode cross-shaped metal mesh filters on thick 525  $\mu\text{m}$  fused silica substrates, which are designed so that they can be scaled to operate throughout the THz band. The use of a substrate means that devices are manufactured by sputter coating the metal layers, then the desired filter pattern is defined by standard photolithography and a wet etch of the metal to realise this pattern within the metal. This process enables us to create geometries that are impossible with the conventional self-supporting metal mesh filters, i.e. crosses within crosses, with no additional supporting structures. Furthermore, since all designs are based on standard 525  $\mu\text{m}$  wafer used in 100mm processing there is no need to thin the wafer during fabrication or use more expensive thinner wafers.

Conventional cross-shaped filters suffer from Fabry–Pérot resonances within the thick substrate. To reduce the effect of these unwanted resonances, and increase the amount of out-of-band rejection above the resonance frequency, a smaller metal cross is placed within the conventional metal cross filter which creates trapped mode excitations, thereby increasing out-of-band rejection. Measurements have been undertaken with Teraview THz-TDS system, which confirm these predictions.

## References

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